TAIWAN SEMICONDUCTOR

RoHS COMPLIANCE

TSM2305

20V P-Channel MOSFET

SOT-23

Pin Definition:
1. Gate
2. Source
3. Drain

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$(mΩ)	I_D (A)
-20	52 @ V_{GS} =-4.5V	-3.2
	71 @ V_{GS} =-2.5V	-2.7
	108 @ V_{GS} =-1.8V	-2.0

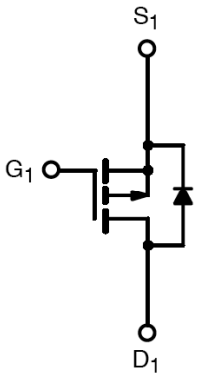
Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Battery Management
- High Speed Switch

Block Diagram



P-Channel MOSFET

Ordering Information

Part No.	Package	Packing
TSM2305CX RFG	SOT-23	3Kpcs / 7" Reel

Note: "G" denotes Halogen Free Product.

Absolute Maximum Rating (T_A=25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±8	V
Continuous Drain Current		I_D	-3.2	A
Pulsed Drain Current		I_{DM}	-10	A
Continuous Source Current (Diode Conduction)[a,b]		I_S	-1	A
Maximum Power Dissipation	T_A=25°C	P_D	1.25	W
	T_A=75°C		0.8	
Operating Junction Temperature		T_J	+150	°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	$R\Theta_{JC}$	80	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	$R\Theta_{JA}$	150	°C/W

Notes:

a. Pulse width limited by the Maximum junction temperature

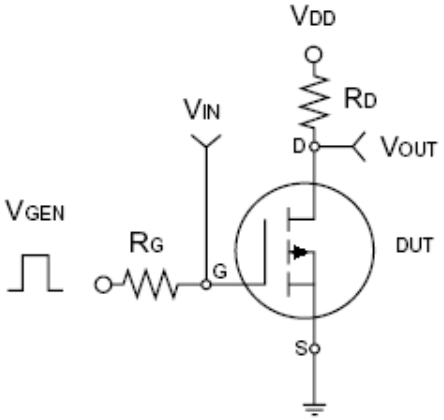
b. Surface Mounted on a 1 in^2 pad of 2oz Cu, t ≤ 10 sec.

TSM2305
20V P-Channel MOSFET

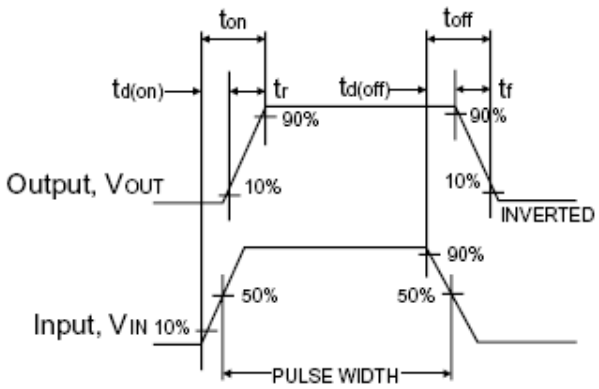
Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	V_{GS} = 0V, I_D = 250µA	BV_{DSS}	-20	--	--	V
Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250µA	$V_{GS(TH)}$	-0.45	-0.7	-1	V
Gate Body Leakage	V_{GS} = ±8V, V_{DS} = 0V	I_{GSS}	--	--	±100	nA
Zero Gate Voltage Drain Current	V_{DS} = -16V, V_{GS} = 0V	I_{DSS}	--	--	1.0	µA
Drain-Source On-State Resistance	V_{GS} = -4.5V, I_D = -3.2A	$R_{DS(ON)}$	--	44	52	mΩ
	V_{GS} = -2.5V, I_D = -2.7A		--	65	71	
	V_{GS} = -1.8V, I_D = -2.0A		--	90	108	
Diode Forward Voltage	I_S = -1A, V_{GS} = 0V	V_{SD}	--	-0.8	-1.3	V
Dynamic[b]						
Gate Resistance	V_{GS} = V_{DS} =0V, f=1MHz	R_g	--	10	--	Ω
Total Gate Charge	V_{DS} = -10V, I_D = -3.2A, V_{GS} = -4.5V	Q_g	--	10	20	nC
Gate-Source Charge		Q_{gs}	--	0.7	--	
Gate-Drain Charge		Q_{gd}	--	4	--	
Input Capacitance	V_{DS} = -10V, V_{GS} = 0V, f = 1.0MHz	C_{iss}	--	990	--	pF
Output Capacitance		C_{oss}	--	125	--	
Reverse Transfer Capacitance		C_{rss}	--	100	--	
Switching[b,c]						
Turn-On Delay Time	V_{DD} = -10V, R_L = 15Ω, I_D = -1A, V_{GEN} = -4.5V, R_G = 6Ω	$t_{d(on)}$	--	12	24	nS
Turn-On Rise Time		t_r	--	23	50	
Turn-Off Delay Time		$t_{d(off)}$	--	50	100	
Turn-Off Fall Time		t_f	--	18	35	

Notes:
a. pulse test: PW ≤300µS, duty cycle ≤2%
b. For DESIGN AID ONLY, not subject to production testing.
c. Switching time is essentially independent of operating temperature.



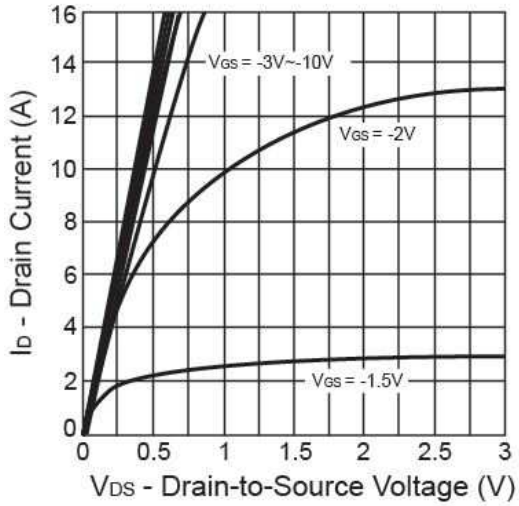
Switching Test Circuit



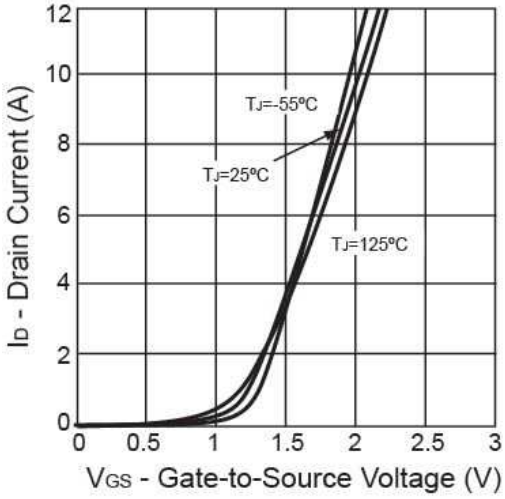
Switchin Waveforms

Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

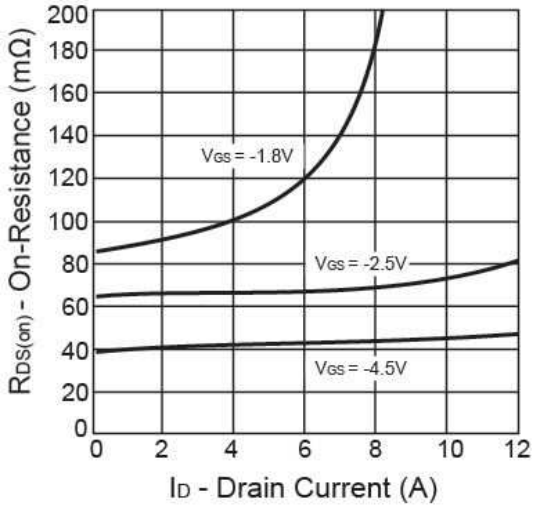
Output Characteristics



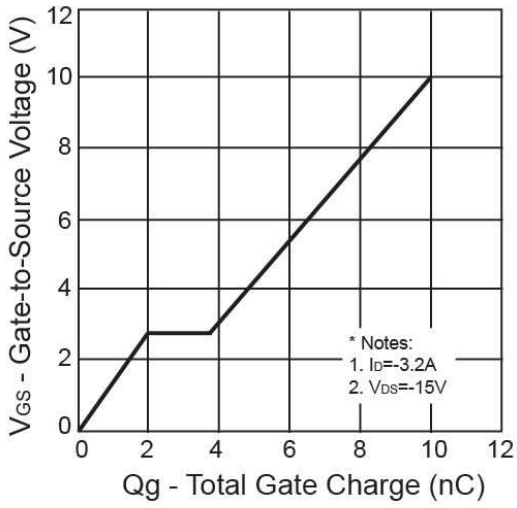
Transfer Characteristics



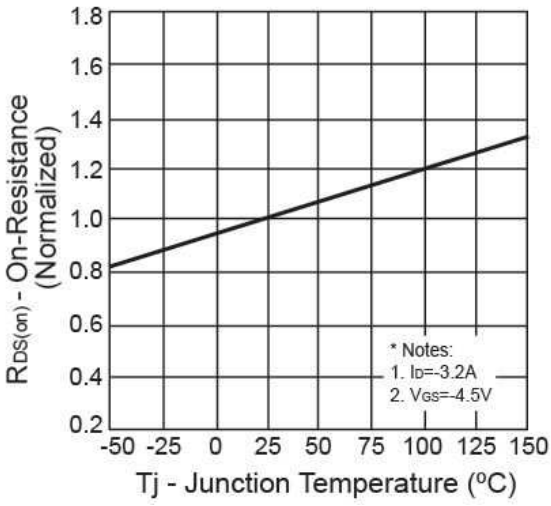
On-Resistance vs. Drain Current



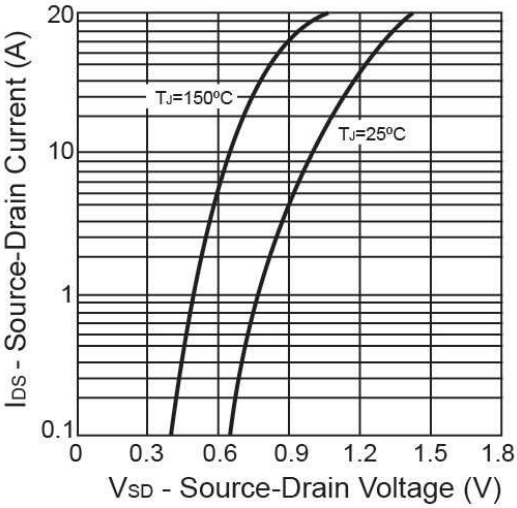
Gate Charge



On-Resistance vs. Junction Temperature

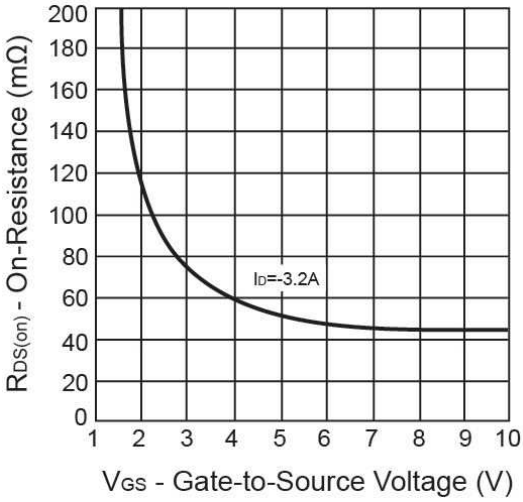


Source-Drain Diode Forward Voltage

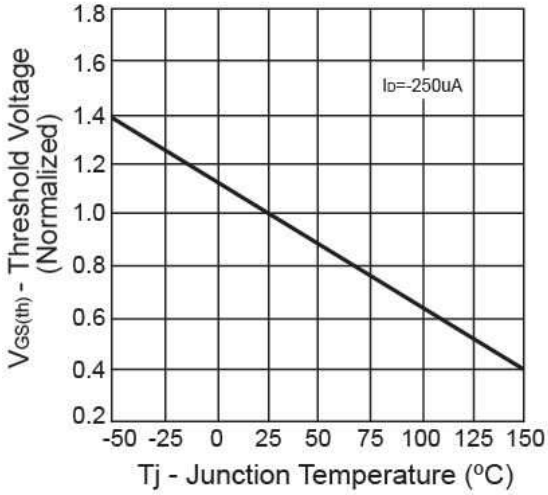


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

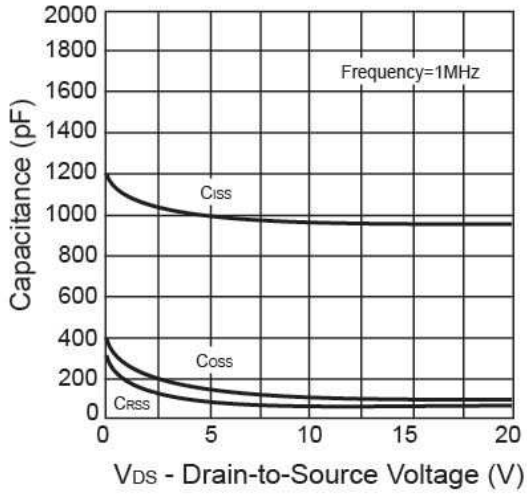
On-Resistance vs. Gate-Source Voltage



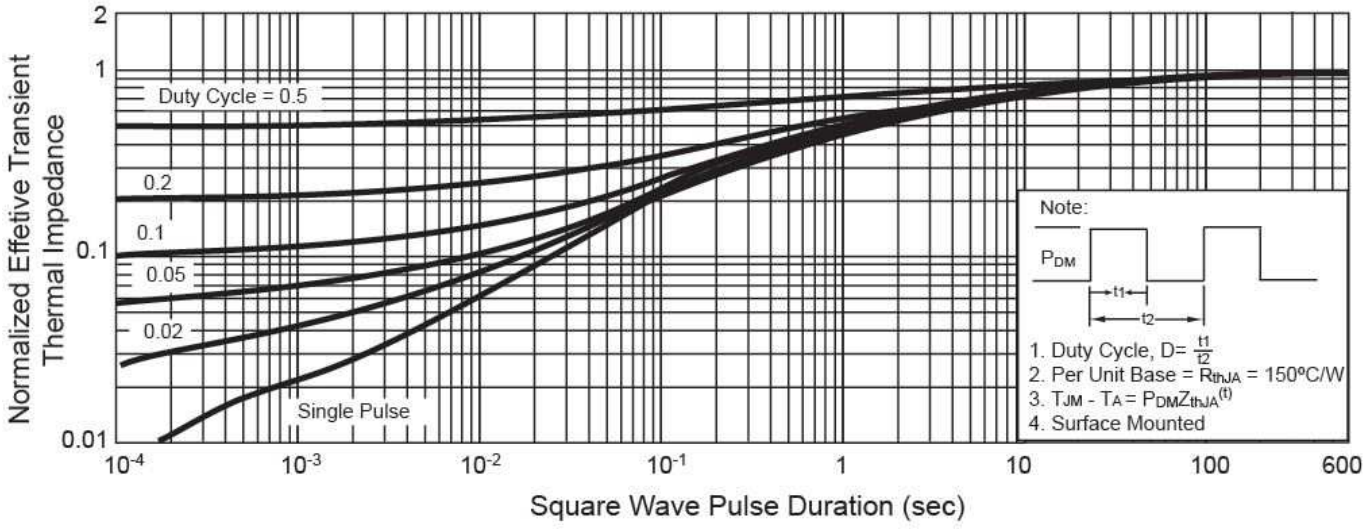
Threshold Voltage



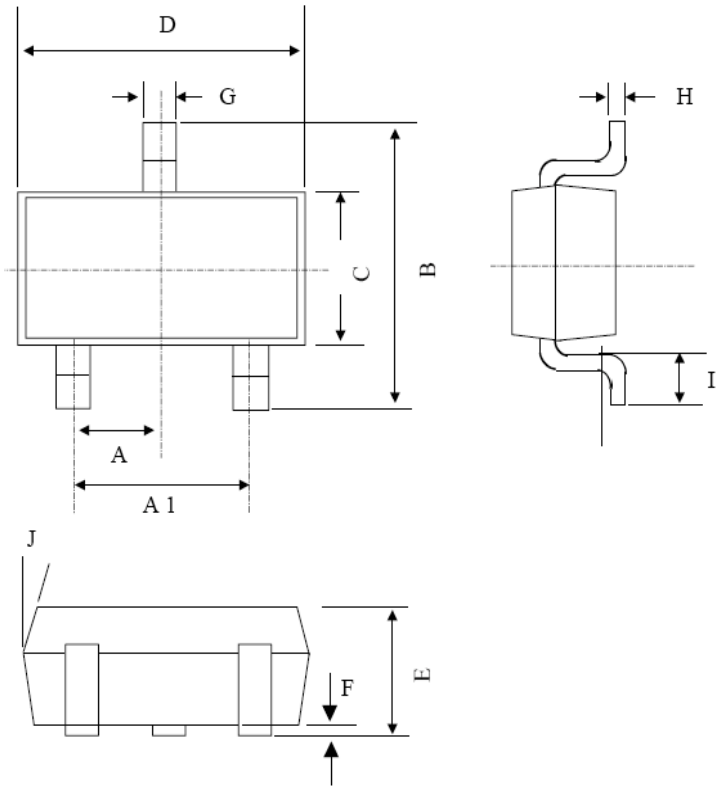
Capacitance



Normalized Thermal Transient Impedance, Junction-to-Ambient

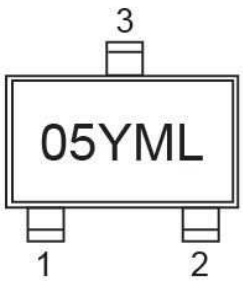


SOT-23 Mechanical Drawing



SOT-23 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX.
A	0.95 BSC		0.037 BSC	
A1	1.9 BSC		0.074 BSC	
B	2.25	2.55	0.089	0.100
C	1.20	1.40	0.047	0.055
D	2.80	3.00	0.110	0.118
E	0.90	1.15	0.035	0.045
F	0.00	0.10	0.000	0.004
G	0.30	0.50	0.012	0.020
H	0.08	0.15	0.003	0.006
I	0.30	0.50	0.012	0.020
J	5º	10º	5º	10º

Marking Diagram



05 = Device Code
Y = Year Code
M = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apl, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)
L = Lot Code

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